NSN 5961-01-179-9193

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-179-9193 **Inclosure Material:** Metal **Overall Length:** Between 0.165 inches and 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-78 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage, dc all transistor and 15.0 collector to emitter voltage, dc all transistor and 3.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector preset all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No